

TECHNICAL DATA DATA SHEET 414, REV. -

SCHOTTKY RECTIFIER Very Low Voltage Drop 200°C Operating Temperature

DESCRIPTION: 100 VOLT, 45 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-258 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ T_{C} = 25 °C UNLESS OTHERWISE SPECIFIED.

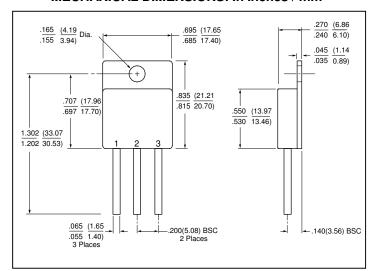
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ T _C =100 ^O C)	Io	45	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT	I _{FSM}	200	Amps
(t = 8.3ms, Sine) (per leg)			
MAXIMUM JUNCTION CAPACITANCE (V _r =5V) (per leg)	C _T	3000	pF
MAXIMUM THERMAL RESISTANCE (per leg)	$R_{ hetaJC}$	0.30	°C/W
MAXIMUM JUNCTION TEMPERATURE RANGE	Тор	-65 to + 200	°C
MAXIMUM STORAGE TEMPERATURE RANGE	Tstg	-65 to + 200	°C

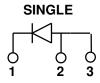
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 45 Amps) (per leg)			
T _J = 25 °C	$V_{\rm f}$	1.04	Volts
T _J = 125 °C	- 1	0.86	
MAXIMUM REVERSE CURRENT (I _r @ 100V PIV) (per leg)			
T _J = 25 °C	l _r	2.0	mA
T _J = 125 °C		48	

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MECHANICAL DIMENSIONS: In Inches / mm



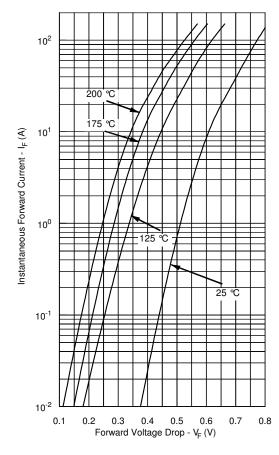


TO-258

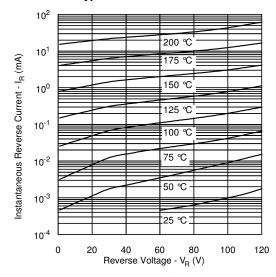
PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE

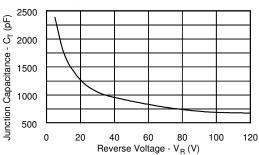
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance





TECHNICAL DATA

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